

Features

- Wide 4V to 30V Operating Input Range
- 3A Continuous Output Current
- Fixed 500KHz Switching Frequency
- No Schottky Diode Required
- Short Protection with Hiccup-Mode
- Built-in Over Current Limit
- Built-in Over Voltage Protection

- Internal Soft start
- Output Adjustable from 0.925V
- Integrated internal compensation
- Thermal Shutdown
- Available in ESOP8 Package
- -40 ℃ to +85 ℃ Temperature Range

Applications

- CCTV Camera
- Flat-Panel Television and Monitor
- Battery Charger
- Distributed Power Systems

General Description

The XR8336 is a high frequency, synchronous, rectified, step-down, switch-mode converter with internal power MOSFETs. It offers a very compact solution to achieve a 4A peak output current over a wide input supply range, with excellent load and line regulation.

The XR8336 requires a minimal number of readily available, external components and is available in a space **ESOPS** package.

Typical Application Circuit

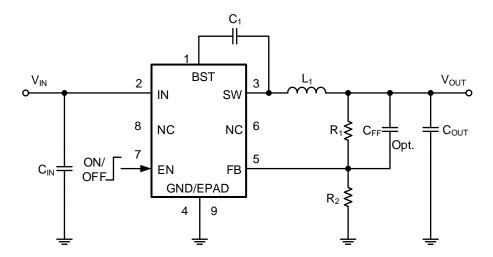


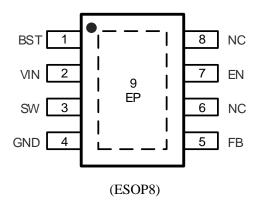
Figure 1. Basic Application Circuit

www.szxunrui.cn Page 1 / **9**



Pin Description

Pin Configuration



Top Marking: GMYLL (device code: GM, Y=year code, LL= lot number code)

Pin Description

Pin	Name	Function		
1	BST	Bootstrap. A capacitor connected between SW and BST pins is required to form a		
1		floating supply across the high-side switch driver.		
2	VIN	Power Supply Pin		
3	SW	Switching Pin		
4/9	GND/EPAD	GROUND Pin		
5	FB	Adjustable Version Feedback input. Connect FB to the center point of the external		
3		resistor divider		
6	NC			
7	EN	Drive this pin to a logic-high to enable the IC. Drive to a logic-low to disable the IC		
		and enter micro-power shutdown mode.		
8	NC			

Order Information

Marking	Part No.	Model	Description	Package	T/R Qty
GM <u>YLL</u>	70301579	XR8336	XR8336 Buck, 4-30V, 3.0A, 500KHz, VFB 0.925V, ESOP8	ESOP8	3000PCS

www.szxunrui.cn Page **2** / **9**



Absolute Maximum Ratings

Vin, EN, Voltage0.3V to 36V	SW Voltage0.3V to (VIN+0.5V)
Operating Temperature Range40 ${\mathbb C}$ to +85 ${\mathbb C}$	Storage Temperature Range65 $^{\circ}$ C to 150 $^{\circ}$ C
FB Voltages0.3 to 6V	BS Voltage (Vsw-0.3) to (Vsw+5V)
Lead Temperature (Soldering, 10s) +300 ℃	ESD (Machine Made) MM
Thermal Resistance (θJA)50 °C/W	ESD (Human Body Made) HMB 2KV
Thermal Resistance (θJC)10 °C/W	

Note1: Exceeding these ratings may damage the device.

Note2: The device is not guaranteed to function outside of its operating conditions.

Electrical Characteristics

($V_{IN}=12V$, $V_{OUT}=5V$, $T_A=25$ °C, unless otherwise noted.)

Parameter	Test Conditions	Min	Тур	Max	Unit
Input Voltage Range		4		30	V
Supply Current in Operation	VEN=3.0V, VFB=1.1V		0.4	0.6	mA
Supply Current in Shutdown	Ven = 0 or $EN = GND$			1	μΑ
Regulated Feedback Voltage	$T_A = 25 \text{°C}, 4V \leq VIN \leq 18V$	0.900	0.925	0.946	V
High-Side Switch On-Resistance			130		mΩ
Low-Side Switch On-Resistance			100		mΩ
High-Side Switch Leakage Current	VEN=0V, Vsw=12V			1	uA
Upper Switch Current Limit	Minimum Duty Cycle	4			A
Oscillation Frequency			0.5		MHz
Maximum Duty Cycle	V _{FB} =0.925V			92	%
Minimum On-Time			80		nS
Minimum Off-Time			150		nS
EN up Threshold	V _{EN} -Rising	1.05	1.15	1.25	V
EN Threshold Hysteresis			140		mV
Soft Start			1.05		mS
Thermal Shutdown			160		°C
Thermal Hysteresis			20		°C

Note1: 100% production test at +25 °C. Specifications over the temperature range are guaranteed by design and characterization.

Note2: Dynamic supply current is higher due to the gate charge being delivered at the switching frequency.

Page 3 / 9



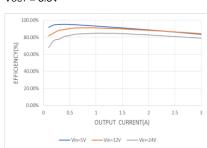
Typical Performance Characteristics

Note (1): Performance waveforms are tested on the evaluation board.

Note (2): $V_{IN} = 12V$, $V_{OUT} = 3.3V$, $T_A = +25$ °C, unless otherwise noted

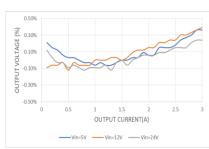
Efficiency vs Load Current

VOUT = 3.3V



Load Regulation

VOUT = 3.3V



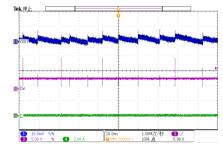
Line Regulation

Vout = 3.3V



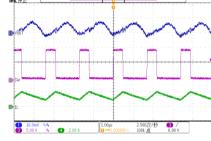
Output Ripple Voltage

VIN = 12V, VOUT = 3.3V, IOUT = 0A



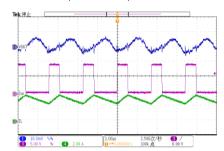
Output Ripple Voltage





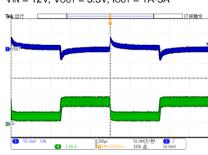
Output Ripple Voltage

Vin = 12V, Vout = 3.3V, Iout = 3A

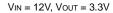


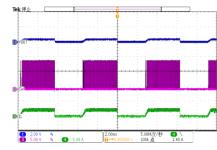
Loop Response

VIN = 12V, VOUT = 3.3V, IOUT = 1A-3A

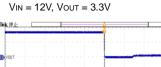


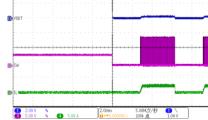
Hiccup with Output Short





Short Circuit Entry

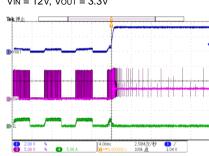




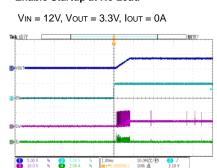


Short Circuit Recovery

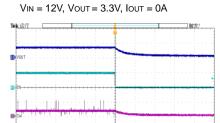
VIN = 12V, VOUT = 3.3V



Enable Startup at No Load

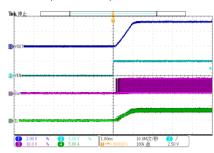


Enable Shutdown at No Load



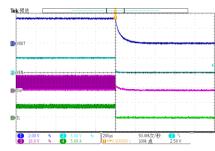
Enable Startup at Full Load

Vin = 12V, Vout = 3.3V, Iout = 3A



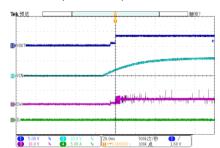
Enable Shutdown at Full Load





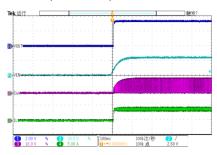
Power Up at No Load

VIN = 12V, VOUT = 3.3V, IOUT = 0A



Power Up at Full Load

Vin = 12V, Vout = 3.3V, Iout = 3A





Functional Block Diagram

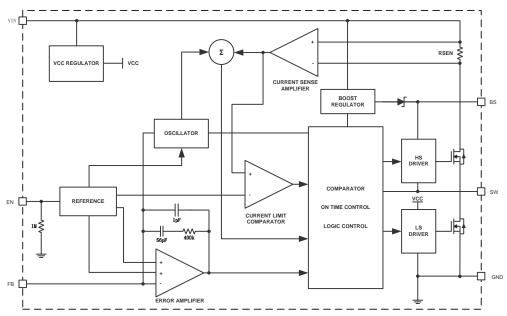


Figure 2. XR8336 Block Diagram

Functions Description

Internal Regulator

The XR8336 is a current mode step down DC/DC converter that provides excellent transient response with no extra external compensation components. This device contains an internal, low resistance, high voltage power MOSFET, and operates at a high 500K operating frequency to ensure a compact, high efficiency design with excellent AC and DC performance.

Error Amplifier

The error amplifier compares the FB pin voltage with the internal FB reference (VFB) and outputs a current proportional to the difference between the two. This output current is then used to charge or discharge the internal compensation network to form the COMP voltage, which is used to control the power MOSFET current. The optimized internal compensation network minimizes the external component counts and simplifies the control loop design.

Internal Soft-Start

The soft-start is implemented to prevent the converter output voltage from overshooting during startup. When the chip starts, the internal circuitry generates a soft-start voltage (SS) ramping up from 0V to 0.925V. When it is lower than the internal reference (REF), SS overrides REF so the error amplifier uses SS as the reference. When SS is higher than REF, REF regains control. The SS time is internally fixed to 1.2ms.

Page **6** / **9** www.szxunrui.cn



Over Current Protection & Hiccup

The XR8336 has cycle-by-cycle over current limit when the inductor current peak value exceeds the set current limit threshold. Meanwhile, output voltage starts to drop until FB is below the Under-Voltage (UV) threshold, typically 25% below the reference. Once a UV is triggered, the XR8336 enters hiccup mode to periodically restart the part. This protection mode is especially useful when the output is dead-short to ground. The average short circuit current is greatly reduced to alleviate the thermal issue and to protect the regulator. The XR8336 exits the hiccup mode once the over current condition is removed.

Startup and Shutdown

If both VIN and EN are higher than their appropriate thresholds, the chip starts. The reference block starts first, generating stable reference voltage and currents, and then the internal regulator is enabled. The regulator provides stable supply for the remaining circuitries. Three events can shut down the chip: EN low, VIN low and thermal shutdown. In the shutdown procedure, the signaling path is first blocked to avoid any fault triggering. The COMP voltage and the internal supply rail are then pulled down. The floating driver is not subject to this shutdown command.

Applications Information

Setting the Output Voltage

XR8336 require an input capacitor, an output capacitor and an inductor. These components are critical to the performance of the device. XR8336 are internally compensated and do not require external components to achieve stable operation. The output voltage can be programmed by resistor divider.

$$V_{OUT} = V_{FEEDBACK} \times \frac{R1 + R2}{R2}$$

V _{OUT}	R1	R2	L1 _{MIN}	L1 _{TYP}	L1 _{MAX}	C _{IN}	C _{OUT}
1V	4.05ΚΩ	50ΚΩ	2.2μΗ	2.2μΗ	4.7μΗ	20-47uF	20-68uF
1.05V	6.76ΚΩ	50ΚΩ	2.2μΗ	2.2μΗ	4.7μΗ	20-47uF	20-68uF
1.2V	14.9ΚΩ	50ΚΩ	2.2μΗ	2.2μΗ	4.7μΗ	20-47uF	20-68uF
1.5V	31.1ΚΩ	50ΚΩ	2.2μΗ	2.2μΗ	4.7μΗ	20-47uF	20-68uF
3.3V	128.4ΚΩ	50ΚΩ	3.3μΗ	3.3μΗ	4.7μΗ	20-47uF	20-68uF
5.0V	220ΚΩ	50ΚΩ	3.3μΗ	4.7μΗ	4.7μΗ	20-47uF	20-68uF

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Selecting the Inductor

The recommended inductor values are shown in the Application Diagram. It is important to guarantee the inductor core does not saturate during any foreseeable operational situation. The inductor should be rated to handle the peak load current plus the ripple current: Care should be taken when reviewing the different saturation current ratings that are specified by different manufacturers. Saturation current ratings are typically specified at 25 °C, so ratings at maximum ambient temperature of the application should be requested from the manufacturer.

$$L = \frac{V_{out} \times (V_{in} - V_{out})}{V_{in} \times \Delta I_L \times f_{OSC}}$$

Where ΔIL is the inductor ripple current. Choose inductor ripple current to be approximately 30% if the maximum load current, 3A. The maximum inductor peak current is:

$$I_{_{L(M\!A\!X\,)}}=I_{_{LO\!A\!D}}+\frac{\Delta I_{_L}}{2}$$

Under light load conditions below 100mA, larger inductance is recommended for improved efficiency.

Selecting the Output Capacitor

Special attention should be paid when selecting these components. The DC bias of these capacitors can result in a capacitance value that falls below the minimum value given in the recommended capacitor specifications table.

The ceramic capacitor's actual capacitance can vary with temperature. The capacitor type X7R, which operates over a temperature range of -55° C to $+125^{\circ}$ C, will only vary the capacitance to within $\pm15\%$. The capacitor type X5R has a similar tolerance over a reduced temperature range of -55° C to $+85^{\circ}$ C. Many large value ceramic capacitors, larger than 1uF are manufactured with Z5U or Y5V temperature characteristics. Their capacitance can drop by more than 50% as the temperature varies from 25 $^{\circ}$ C to 85 $^{\circ}$ C. Therefore X5R or X7R is recommended over Z5U and Y5V in applications where the ambient temperature will change significantly above or below 25 $^{\circ}$ C.

Tantalum capacitors are less desirable than ceramic for use as output capacitors because they are more expensive when comparing equivalent capacitance and voltage ratings in the $0.47 \mathrm{uF}$ to $44 \mathrm{uF}$ range. Another important consideration is that tantalum capacitors have higher ESR values than equivalent size ceramics. This means that while it may be possible to find a tantalum capacitor with an ESR value within the stable range, it would have to be larger in capacitance (which means bigger and more costly) than a ceramic capacitor with the same ESR value. It should also be noted that the ESR of a typical tantalum will increase about 2:1 as the temperature goes from $25 \, ^{\circ}\mathrm{C}$ down to $-40 \, ^{\circ}\mathrm{C}$, so some guard band must be allowed.

PC Board Layout Consideration

PCB layout is very important to achieve stable operation. It is highly recommended to duplicate EVB layout for optimum performance. If change is necessary, please follow these guidelines and take Figure 4 for reference.

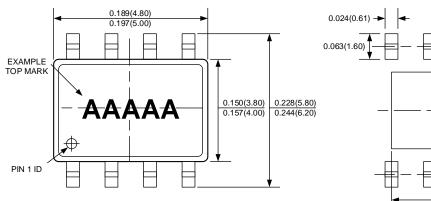
- 1. Keep the path of switching current short and minimize the loop area formed by Input capacitor, high-side MOSFET and low-side MOSFET.
- 2. Bypass ceramic capacitors are suggested to be put close to the Vin Pin.
- 3. Ensure all feedback connections are short and direct. Place the feedback resistors and compensation components as close to the chip as possible.
- 4. VOUT, SW away from sensitive analog areas such as FB.
- 5. Connect IN, SW, and especially GND respectively to a large copper area to cool the chip to improve thermal performance and long-term reliability.

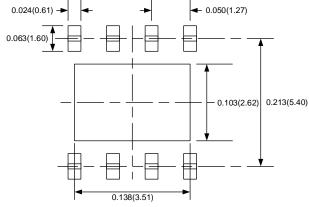
www.szxunrui.cn Page **8** / **9**



Package Description

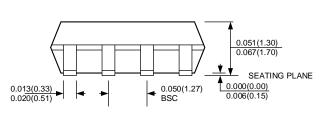
ESOP8 (EXPOSED PAD)



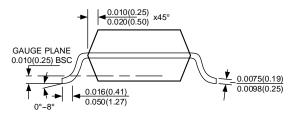


TOP VIEW

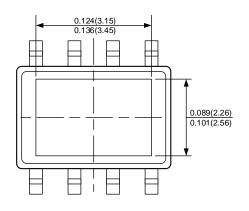
RECOMMENDED PAD LAYOUT



FRONT VIEW



SIDE VIEW



BOTTOM VIEW

NOTE:

- 1. CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
- 2. PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 3. PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
- 4. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
- 5. DRAWING CONFORMS TO JEDEC MS-012, VARIATION BA.
- 6. DRAWING IS NOT TO SCALE.